

# 产品规格书

批 准	审 核	校核	编 制
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2018.09.07	2018.09.07	2018.09.07	2018.09.07

#### 规格书更改履历:

序号	更改内容	履历号	更改时间	责任人
1	新规制定	000	2018. 03. 02	郑羿
2	增加 TAPING 标准	001	2018. 09. 07	郑羿





**NPN Silicon Transistor** 

#### **Descriptions**

- General small signal application
- Switching application

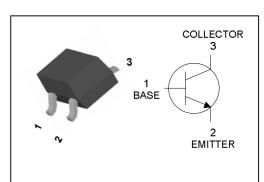
#### **Features**

- Low collector saturation voltage
- Collector output capacitance
- Complementary pair with KBT3906C

### **Ordering Information**

Type NO.	Marking	Package Code
KBT3904C	<u>1A</u> □• ① ②	SOT-23

①Device Code ②Year& Week Code • Dalian



**PIN Connection** 

### Absolute maximum ratings

Ta=25°C

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	$V_{CBO}$	60	V
Collector-Emitter voltage	$V_{\sf CEO}$	40	V
Emitter-base voltage	$V_{EBO}$	6	V
Collector current	$I_{C}$	200	mA
Collector dissipation	$P_{C}$	350	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature range	T <sub>stq</sub>	-55~150	°C

## **Electrical Characteristics**

Ta=25°C

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> =10uA, I <sub>E</sub> =0	60	-	-	V
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	$I_C=1$ mA, $I_B=0$	40	-	-	V
Emitter-Base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> =10uA, I <sub>C</sub> =0	6	-	-	V
Collector cut-off current	I <sub>CEX</sub>	V <sub>CE</sub> =30V, V <sub>BE(Off)</sub> =3V	-	1	50	nA
DC current gain	h <sub>FE1</sub>	V <sub>CE</sub> =1V, I <sub>C</sub> =10mA	100	-	300	-
Collector-Emitter saturation voltage	$V_{CE(sat)}$	I <sub>C</sub> =50mA, I <sub>B</sub> =5mA	-	-	0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE}$ =20V, $I_{C}$ =10mA, $f$ =100MHz	300	-	-	MHz
Collector output capacitance	Cob	$V_{CB}$ =5V, $I_E$ =0,f=1MHz	-	-	4	pF
Delay time	t <sub>d</sub>	$V_{CC}=3V_{dc}$ , $V_{BE(OFF)}=0.5V$	-	-	35	ns
Rise time	t <sub>r</sub>	$I_C=10\text{mA}_{dc}, I_{B1}=1\text{mA}_{dc}$	-	-	35	ns
Storage time	t <sub>s</sub>	$V_{CC}=3V_{dc}$ , $I_{C}=10\text{mA}_{dc}$ ,	-	-	200	ns
Fall time	t <sub>f</sub>	$I_{B1} = I_{B2} = 1 \text{mA}_{dc}$	-	-	50	ns

### **Electrical Characteristic Curves**

Fig. 1 P<sub>C</sub>.T<sub>a</sub>

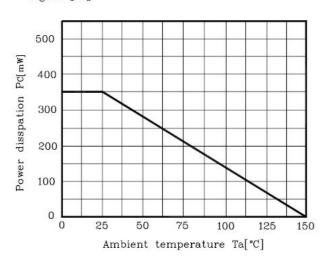


Fig. 2 hFE.IC

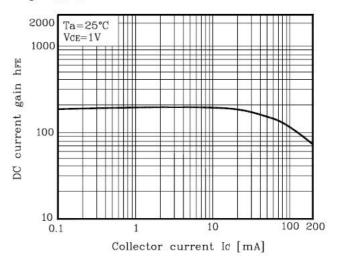
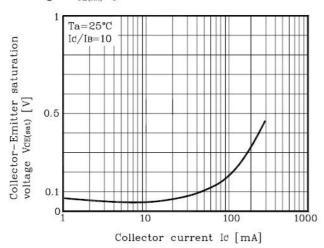
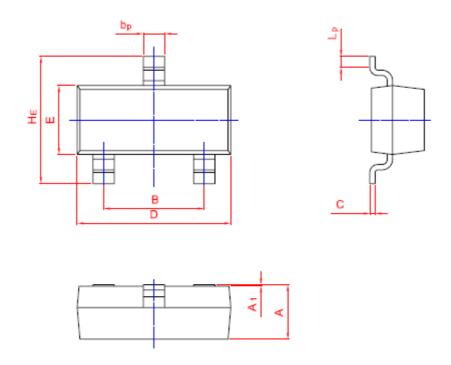


Fig. 3 V<sub>CE(sat)</sub>-I<sub>C</sub>

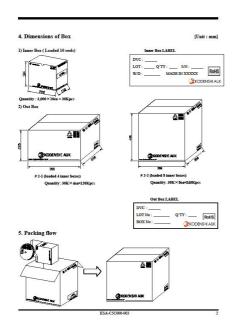


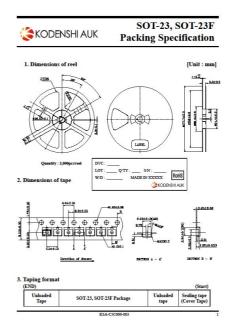
## **Outline Dimension**



UNIT	Α	В	bp	С	D	E	HE	<b>A</b> 1	Lp
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	

#### **Packing Specification**





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